	Туре	Hits	Search Text	DBs	Time Stamp	C Er o ro e m r r m De r en fin ts iti
1	BRS	0	ridge and semiconductor and clad\$4 and (current near block\$3) and gasa and gainp and algainp	USPAT; US-PGPUB	2003/02/03 17:46	o
2	BRS	0	ridge and semiconductor and clad\$4 and (current near block\$3) and gasa and gainp	USPAT; US-PGPUB	2003/01/29 11:29	0
3	BRS	109	ridge and semiconductor and clad\$4 and (current near block\$3) and gaas and gainp and algainp	USPAT; US-PGPUB	2003/01/30 12:45	O
4	BRS	29	(ridge and semiconductor and clad\$4 and (current near block\$3) and gaas and gainp and algainp) and bandgap	USPAT; US-PGPUB	2003/01/29 11:31	O
5	BRS	20	semiconductor and clad\$4 and (current near block\$3) and gaas and gainp and algainp and bandgap and (carrier near concentration)	USPAT; US-PGPUB	2003/01/30 13:24	o
6	BRS	21	semiconductor and clad\$4 and (current near block\$3) and algainp and bandgap and (carrier near concentration) and ridge	USPAT; US-PGPUB	2003/01/30 13:25	O
7	BRS	6697	depletion near layer	USPAT; US-PGPUB	2003/02/03 17:46	0
8	BR\$	0	(depletion near layer) and (etch near stop near alyer)	USPAT; US-PGPUB	2003/02/03 17:47	
9	BRS	53	(depletion near layer) and (etch near stop near layer)	USPAT; US-PGPUB	2003/02/03 17:55	0
10	BRS	88	(depletion near layer) and ridge	USPAT; US-PGPUB	2003/02/03 17:55	0
11	BRS	476	(depletion near layer) and stripe	USPAT; US-PGPUB	2003/02/03 17:55	0
12	BRS	19	(depletion near layer) and (current near block\$3) and clad\$4 and ridge	USPAT; US-PGPUB	2003/02/03 18:02	0
13	BRS	43	(depletion near layer) and (current near block\$3) and clad\$4 and stripe	USPAT; US-PGPUB	2003/02/03 18:02	0

BEST AVAILABLE COPY

02/04/2003, EAST Version: 1.03.0002